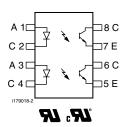


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# Optocoupler, Phototransistor Output, Dual Channel, SOIC-8 Package





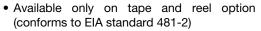
### **DESCRIPTION**

The ILD205T, ILD206T, ILD207T, ILD211T, and ILD213T are optically coupled pairs with a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD205T, ILD206T, ILD207T, ILD211T, and ILD213T come in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited space. In addition to eliminating through-holes requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high  $BV_{CEO}$  of 70 V gives a higher safety margin compared to the industry standard of 30 V.

### **FEATURES**

- Two channel coupler
- SOIC-8 surface mountable package
- Standard lead spacing of 0.05"

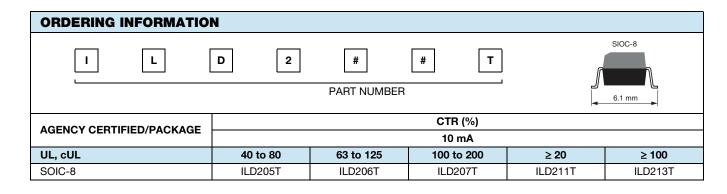




- Isolation test voltage, 4000 V<sub>RMS</sub>
- Compatible with dual wave, vapor phase and IR reflow soldering
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL file no. E52744, equivalent to CSA bulletin 5A



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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Peak reverse voltage		V <sub>R</sub>	6	V			
Peak pulsed current	1 µs, 300 pps		1	Α			
Continuous forward current per channel		I <sub>F</sub>	30	mA			
Power dissipation		P <sub>diss</sub>	50	mW			
OUTPUT		<u> </u>		•			
Collector emitter breakdown voltage		BV <sub>CEO</sub>	70	V			
Emitter collector breakdown voltage		BV <sub>ECO</sub>	7	V			
Power dissipation per channel		P <sub>diss</sub>	125	mW			
COUPLER							
Total package dissipation ambient (2 LEDs and 2 detectors, 2 channels)		P <sub>tot</sub>	350	mW			
Storage temperature		T <sub>stg</sub>	-55 to +150	°C			
Operating temperature		T <sub>amb</sub>	-55 to +100	°C			
Soldering time from 260 °C <sup>(1)</sup>		T <sub>sld</sub>	10	S			

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	$I_F = 10 \text{ mA}$	$V_{F}$	-	1.2	1.55	V	
Reverse current	V <sub>R</sub> = 6 V	I <sub>R</sub>	-	0.1	100	μA	
Capacitance	$V_R = 0 V$	Co	-	25	-	pF	
OUTPUT							
Collector emitter breakdown voltage	$I_C = 10 \mu A$	BV <sub>CEO</sub>	70	-	-	V	
Emitter collector breakdown voltage	$I_E = 10 \mu A$	BV <sub>ECO</sub>	7	-	-	V	
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}$	I <sub>CEO</sub>	-	5	50	nA	
Collector emitter capacitance	V <sub>CE</sub> = 0 V	C <sub>CE</sub>	-	10	-	pF	
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$	V <sub>CEsat</sub>	=	-	0.4	V	
Capacitance (input to output)		C <sub>IO</sub>	-	0.5	-	pF	

#### Note

• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I <sub>C</sub> /I <sub>F</sub>	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA	ILD205T	CTR <sub>DC</sub>	40	-	80	%
		ILD206T	CTR <sub>DC</sub>	63	-	125	%
		ILD207T	CTR <sub>DC</sub>	100	-	200	%
		ILD211T	CTR <sub>DC</sub>	20	-	-	%
		ILD213T	CTR <sub>DC</sub>	100	-	-	%
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 1 mA	ILD205T	CTR <sub>DC</sub>	13	30	-	%
		ILD206T	CTR <sub>DC</sub>	22	45	-	%
		ILD207T	CTR <sub>DC</sub>	34	70	-	%

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<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>d</sub>	-	3	-	μs	
Rise time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>r</sub>	-	3	-	μs	
Fall time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>f</sub>	-	4.7	-	μs	
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t <sub>s</sub>	-	0.3	-	μs	
Turn-on time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>on</sub>	-	6	-	μs	
Turn-off time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>off</sub>	-	5	-	μs	
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t <sub>on</sub>	-	3	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t <sub>off</sub>	-	10	-	μs	

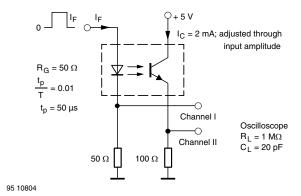


Fig. 1 - Test Circuit, Non-Saturated Operation

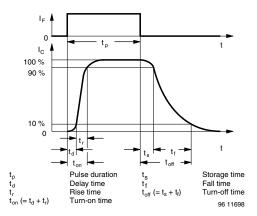


Fig. 3 - Switching Times

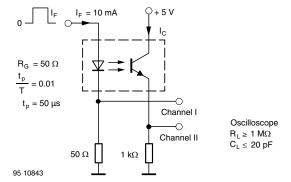


Fig. 2 - Test Circuit, Saturated Operation

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SAFETY AND INSULATION RATINGS	S			
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55/100/21	
Comparative tracking index		CTI	175	
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V <sub>ISO</sub>	4000	V <sub>RMS</sub>
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	6000	V <sub>peak</sub>
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V <sub>IORM</sub>	560	V <sub>peak</sub>
Isolation resistance	$T_{amb} = 25  ^{\circ}\text{C},  V_{IO} = 500  \text{V}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
isolation resistance	$T_{amb} = 100  ^{\circ}\text{C},  V_{IO} = 500  \text{V}$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Output safety power		P <sub>SO</sub>	350	mW
Input safety current		I <sub>SI</sub>	150	mA
Input safety temperature		Ts	165	°C
Creepage distance	DIP-6, option 6		4	mm
Clearance distance	DIP-6, option 6		4	mm
Insulation thickness			0.2	mm

#### Note

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

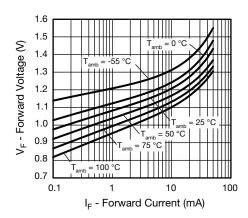


Fig. 4 - Forward Voltage vs. Forward Current

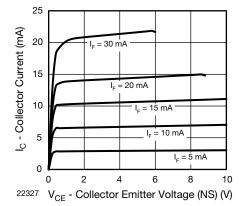


Fig. 5 - Collector Current vs. Collector Emitter Voltage (non-saturated)

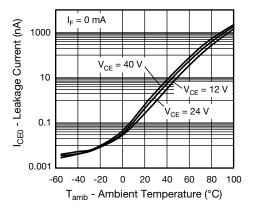


Fig. 6 - Leakage Current vs. Ambient Temperature

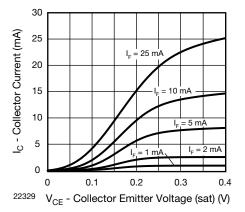


Fig. 7 - Collector Current vs. Collector Emitter Voltage (saturated)

<sup>•</sup> As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

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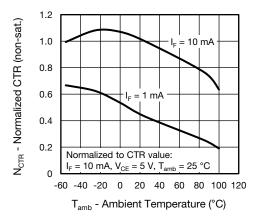


Fig. 8 - Normalized CTR (saturated) vs. Ambient Temperature

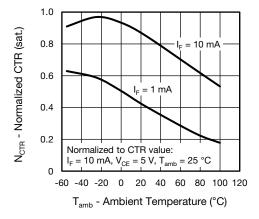


Fig. 9 - Normalized CTR (non-saturated) vs. Ambient Temperature

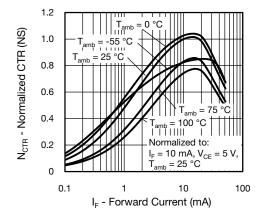


Fig. 10 - Normalized CTR (non-saturated) vs. Forward Current

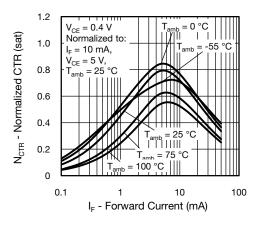


Fig. 11 - Normalized CTR (saturated) vs. Forward Current

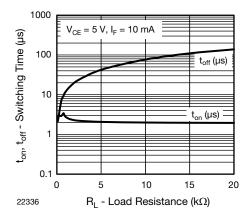


Fig. 12 - Switching Time vs. Load Resistance

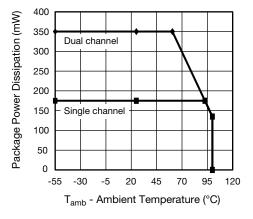
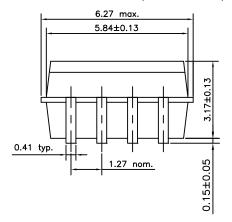


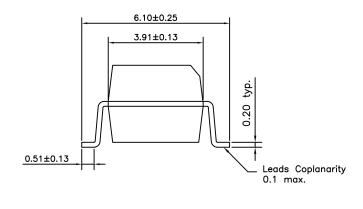
Fig. 13 - Power Dissipation vs. Ambient Temperature

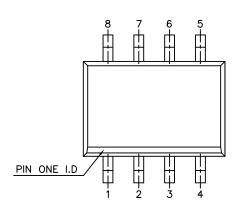


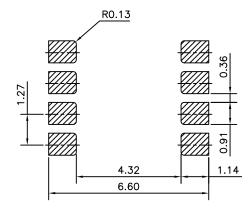
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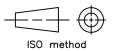
### **PACKAGE DIMENSIONS** (in millimeters)











### **PACKAGE MARKING** (example)



### Note

• Tape and reel suffix (T) is not part of the package marking.

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### TAPE AND REEL PACKAGING FOR DUAL CHANNELS (1) (in millimeters)

Selected dual SOIC8 optocouplers are available in tape and reel format. To order surface mount ILD2XX optocoupler on tape and reel, add a suffix "T" after the part number, i.e., ILD207T.

The tape is 16 mm and is wound on a 33 cm reel. There are 2000 parts per reel. Taped and reeled dual SOIC8 optocouplers conform to EIA-481-2 and IEC 60286-3.

#### Note

(1) Select dual channel devices are available in the shorter SOIC-8 package and will be taped according to the single channel taping specification

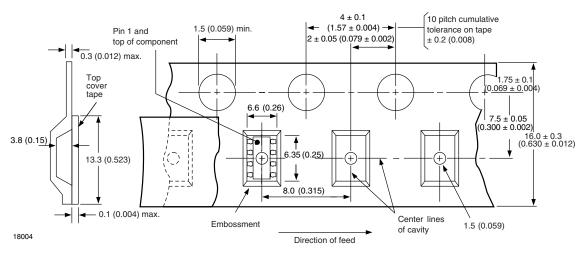


Fig. 14

### **SOLDER PROFILE**

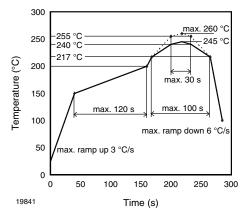


Fig. 15 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020

### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T<sub>amb</sub> < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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